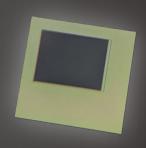
TOPPAN

TPHT4040

1/4 Type, VGA, 3D ToF Sensor

Engineering Sample



The TPHT4040 is a 3D time-of-flight (ToF) sensor that employs TOPPAN's unique pixel structure optimized for our short pulse ToF sensing. It is fabricated in a back-illuminated CMOS process which enhances high sensitivity in the near-infrared region. In addition, this sensor features TOPPAN's proprietary hybrid ToF technology which combines a short pulse ToF method and our patented multi-time window sensing technique. This combination ensures accurate 3D depth sensing without motion artifacts and blurs, and offers high ambient light tolerance for outdoor use. It also supports a high dynamic range (HDR) operation mode and high-speed operation mode up to 120fps. The sensor output employs the MIPI CSI-2 high-speed interface widely used in back-end SoCs. Furthermore, it offers the deep power-down mode that can dramatically reduce power consumption in standby state, enabling long-lasting operation of battery-powered devices. The TPHT4040 is well-suited for diverse 3D sensing applications, such as AGV/AMR, robotics, factory use, gaming devices, and security.

Features

- Less motion artifacts and blurs with TOPPAN's short pulse ToF sensing method
- High ambient light tolerance (100,000lx) for indoor and outdoor use
- Supports high frame rates up to 120fps
- Features a deep power-down mode that significantly reduces the power consumption in standby state
- Avoids ToF signal interference between ToF cameras in the same environment with smart interference cancellation function
- Available for signal HDR and 4×4 pixel binning functions to improve ranging performances with reduced temporal depth noise, and a region of interest (ROI) function

Application

- Small mobility devices (AGV / AMR, drones, ...etc.)
- Robotics and Factory Automation
- Gaming devices
- Smart Glasses (VR/AR)
- · Security and Surveillance

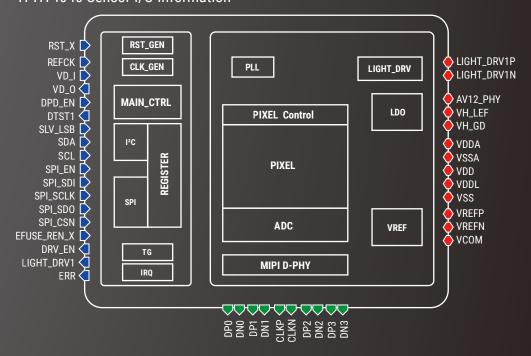
Specifications

These specifications may be changed in mass production for the purpose of performance and quality improvement.

3D ToF Sensing method	Short pulse type
Optical format	1/4 Type
Die size	6.06mm × 5.87mm
Pixel size	5.6μm × 5.6μm
Active pixel area	640(H) × 480(V); VGA
	160(H) × 120(V); 4x4 Binning
Tempareture sensor	Yes
Framerate	30fps(тур.), мах.120fps(3-tap, 4 lane); VGA
Framerate Shutter type	30fps(Typ.), Max.120fps(3-tap, 4 lane); VGA Global shutter
Shutter type	Global shutter
Shutter type	Global shutter 12-bit on-chip
Shutter type ADC resolution	Global shutter 12-bit on-chip 640(H) × 480(V); FULL(VGA)

Register control I/FI²C, SPIOutput data I/FMIPI D-PHY CSI-2 2/4 data and 1 clock lanesOutput data formatRAW12Output datarate672Mbps / laneInput clock frequency24MHzOperation temareture-20°C ~ 70°CPower supply voltage3.3V / 1.2VPower consumption290mW @30fps 5mW @Deep power down stateSensor I/O99pinsQ.E.30% @940nmChip delivery formWafer (or Bare chip) 100pin-CQFP (for Evaluation sample)		
Output data I/F 2/4 data and 1 clock lanes Output data format RAW12 Output datarate 672Mbps / lane Input clock frequency 24MHz Operation temareture Power supply voltage 3.3V / 1.2V Power consumption Power consumption Sensor I/O Q.E. 2/4 data and 1 clock lanes 672Mbps / lane 24MHz 290°C ~ 70°C 290°M @30fps 5mW @Deep power down state 99pins Q.E. 30% @940nm Wafer (or Bare chip)	Register control I/F	I ² C, SPI
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Output datarate 672Mbps / lane Input clock frequency 24MHz Operation temareture -20°C ~ 70°C Power supply voltage 3.3V / 1.2V Power consumption 290mW @30fps 5mW @Deep power down state Sensor I/O 99pins Q.E. 30% @940nm Wafer (or Bare chip)		2/4 data and 1 clock lanes
Input clock frequency Operation temareture -20°C ~ 70°C Power supply voltage 3.3V / 1.2V 290mW @30fps 5mW @Deep power down state Sensor I/O 99pins Q.E. 30% @940nm Wafer (or Bare chip)	Output data format	RAW12
Operation temareture -20°C ~ 70°C Power supply voltage 3.3V / 1.2V 290mW @30fps 5mW @Deep power down state Sensor I/O 99pins Q.E. 30% @940nm Wafer (or Bare chip)	Output datarate	672Mbps / lane
Power supply voltage 290mW @30fps 5mW @Deep power down state Sensor I/O 99pins Q.E. 30% @940nm Wafer (or Bare chip)	Input clock frequency	24MHz
Power consumption 290mW @30fps 5mW @Deep power down state Sensor I/O 99pins Q.E. 30% @940nm Wafer (or Bare chip)	Operation temareture	-20℃ ~ 70℃
Sensor I/O Q.E. Sensor I/O 99pins Q.E. 30% @940nm Wafer (or Bare chip)	Power supply voltage	3.3V / 1.2V
Sensor I/O 99pins Q.E. 30% @940nm Wafer (or Bare chip)	Power consumption	290mW @30fps
Q.E. 30% @940nm Chip delivery form Wafer (or Bare chip)		5mW @Deep power down state
Chip delivery form	Sensor I/O	99pins
Chip delivery form	Q.E.	30% @940nm
100pin-CQFP (for Evaluation sample)	Chip delivery form	Wafer (or Bare chip)
		100pin-CQFP (for Evaluation sample)

TPHT4040 Sensor I/O Information







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